

Tera-Pixel APS for CALICE

Progress meeting, 12th July 2006

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Phone meeting with Foundry (June 19th)

- **Foundry Actions:**

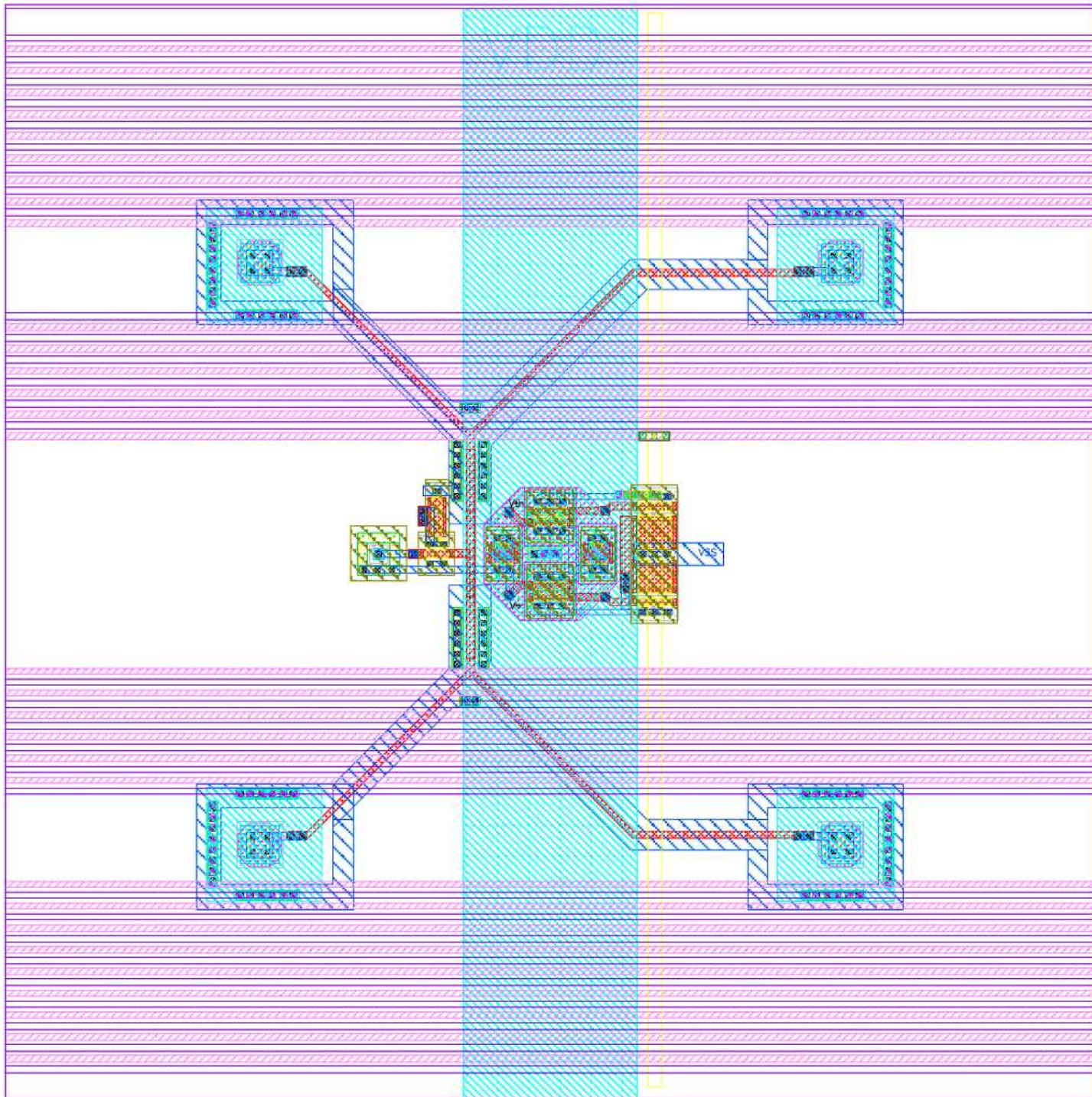
- Check the possibility of performing process splits in Shuttle run *à Yes this is possible*
- Check the availability of the corner model for Deep N-well Diode - dnwell33 *à No model avail.*
- Check the availability of the GDS files of the following IO pad libraries:
 - staggered analog pads
 - PCI inline pads
- Check if Foundry offers large IO pads (100um x 100um) both for Analog and Digital
- Send Rutherford the shuttle schedule for the beginning of 2007

} *pending*

- **Rutherford Actions:**

- Send Foundry a draft of Calice project *à Sent example pixel GDS*
- Send Foundry Rutherford's requirements for TCAD tool both for MI3 and Calice projects. *à Sent summary document (details from Giulio)*
- Fill out and send Foundry the CIS Application General Questionnaire for Calice project (see attached)

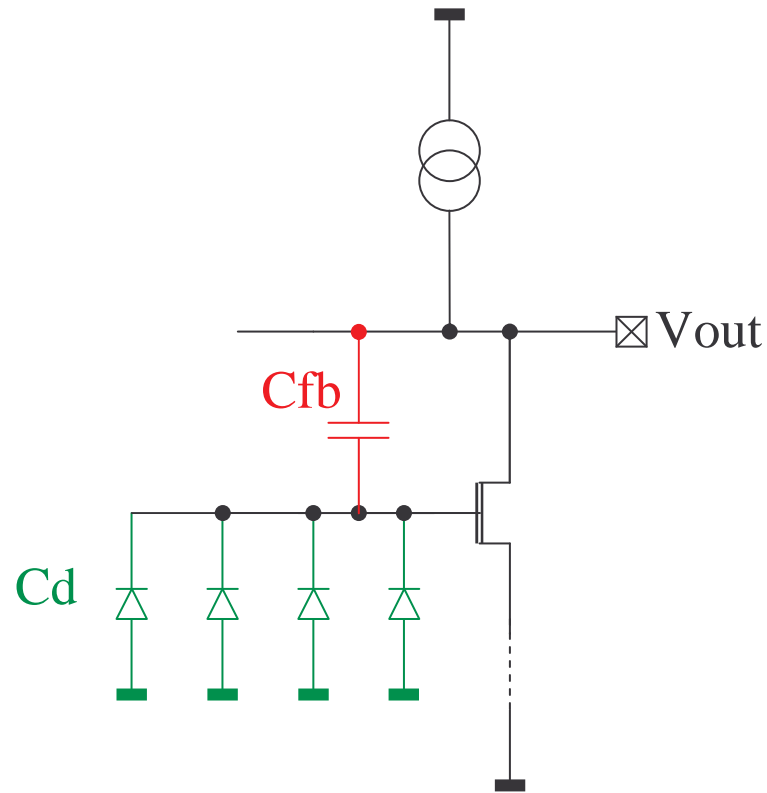
Demo Pixel



Analog Pixel

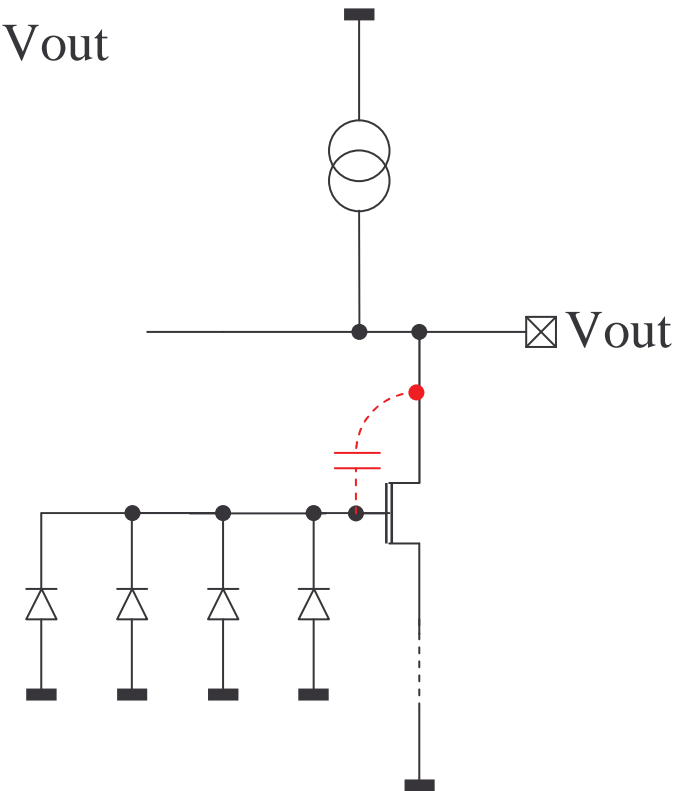
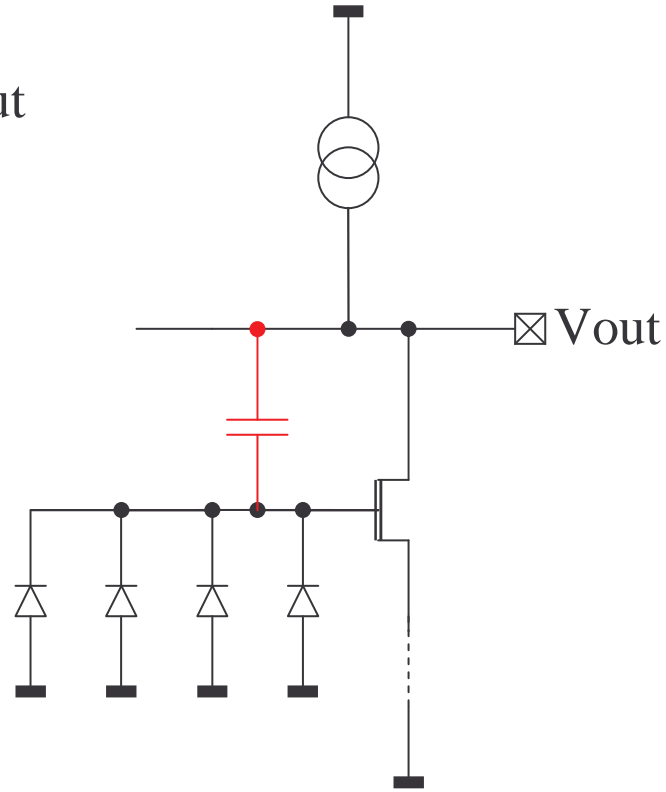
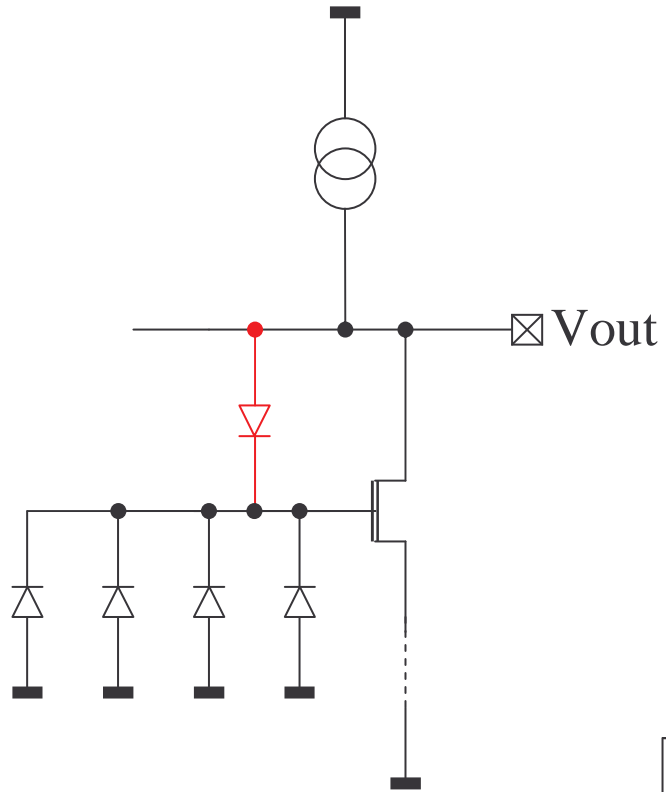
- Voltage amplifiers disappointing
- Charge amplifiers may be more appropriate
- Autozero comparator may be too complex
 - Clock line switching in every pixel
- Simpler comparator design possible if we can reset the pixel after a hit?

Charge Amplifier



- ⌘ Smaller C_{fb} → Larger output step
- ⌘ Charge-to-voltage gain is independent of C_d (hence can have 4 diodes in parallel)
- ⌘ Larger voltage step at output than seen before
- ⌘ Purely capacitive feedback requires a reset phase
- ⌘ Diode feedback provides resistive ‘biasing’ feedback
- ⌘ No corner of MonteCarlo models for diode
- ⌘ Parasitic feedback subject to layout and accuracy of 3D parasitic extraction tools!

Charge Amplifiers



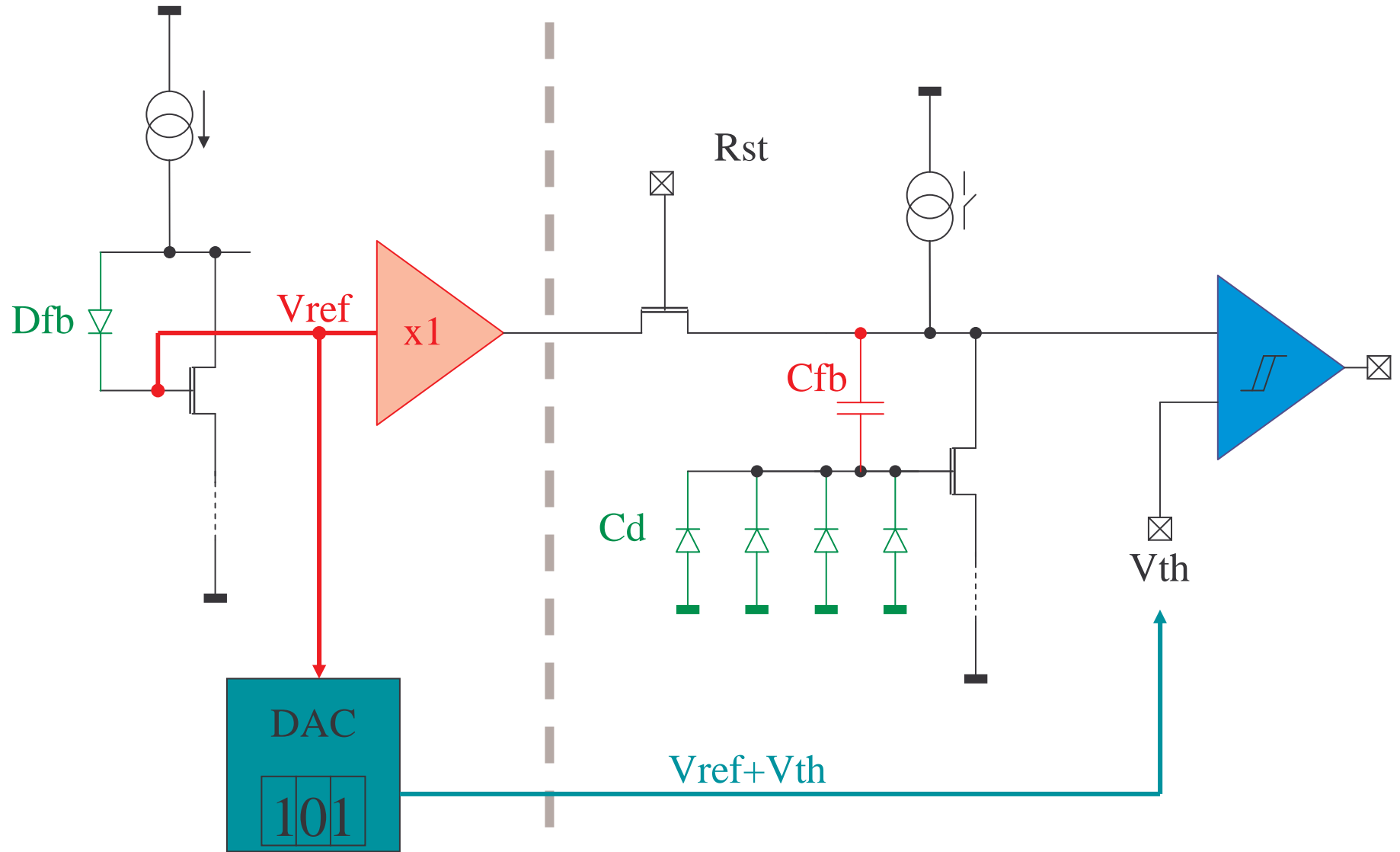
Diode feedback

Capacitor feedback

Parasitic Capacitance feedback

Local Reference

Active Pixel(s)



		Diode feedback			MIM-cap feedback			Parasitic-cap feedback			
Number of pmos		1			1			1			
Vdd		2.5			2.5			2.5			
Static current		500nA			500nA			500nA			
Process Corners		<u>Slow</u>	<u>Typ</u>	<u>Fast</u>	<u>Slow</u>	<u>Typ</u>	<u>Fast</u>	<u>Slow</u>	<u>Typ</u>	<u>Fast</u>	
Vout step (450e-)	4diode	49.0	45.1	39.5	15.4	14.4	14.5	59.7	55.7	51.2	
Voltage Gain											
DC diode voltage											
DC output voltage											
Final value (DC o/p)											
Noise											

